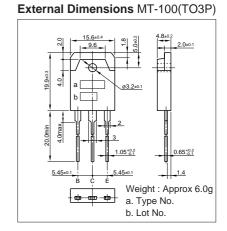
2SC3678

Silicon NPN Triple Diffused Planar Transistor (High Voltage Switching Transistor)

Application: Switching Regulator and General Purpose

Absolute maximum ratings (Ta=25°C					
Symbol	2SC3678	Unit			
Vсво	900	V			
VCEO	800	V			
VEBO	7	V			
Ic	3(Pulse6)	А			
Ів	1.5	А			
Pc	80(Tc=25°C)	W			
Tj	150	°C			
Tstg	-55 to +150	°C			

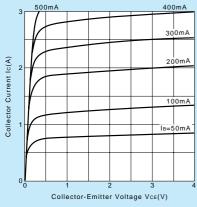
Electrical C	haracteristics	(Ta=25°C)		
Symbol	Conditions	2SC3678	Unit	
Ісво	Vcb=800V	100max	μΑ	
І ЕВО	VEB=7V	100max	μΑ	
V(BR)CEO	Ic=10mA	800min	V	
hfe	Vce=4V, Ic=1A	10 to 30		
Vce(sat)	Ic=1A, IB=0.2A	0.5max	V	
VBE(sat)	Ic=1A, IB=0.2A	1.2max	V	
fr	Vce=12V, Ie=-0.3A	6typ	MHz	
Сов	VcB=10V, f=1MHz	50typ	pF	



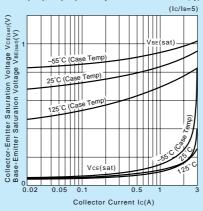
Typical Switching Characteristics (Common Emitter)

71	- · · · · · · · ·				,				
Vcc (V)	RL (Ω)	Ic (A)	V _{BB1} (V)	VBB2 (V)	IB1 (A)	IB2 (A)	ton (µs)	tstg (µs)	tf (µs)
250	250	1	10	-5	0.15	-0.5	1max	5max	1max

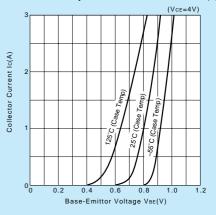




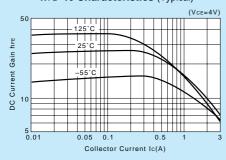
VcE(sat), VBE(sat)-Ic Temperature Characteristics (Typical)



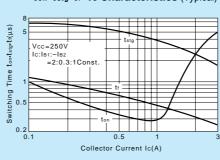
Ic-VBE Temperature Characteristics (Typical)



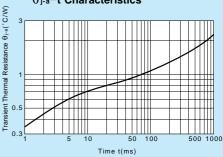
hfe-Ic Characteristics (Typical)



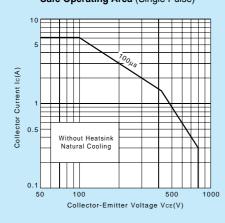
ton•tstg•tf-Ic Characteristics (Typical)



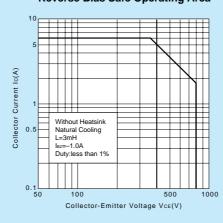
θ_{j-a}-t Characteristics



Safe Operating Area (Single Pulse)



Reverse Bias Safe Operating Area



Pc-Ta Derating

